

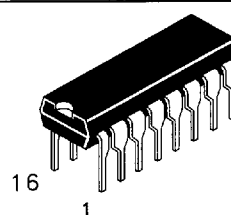
DV74HCT109 Available Q2, 1995

Dual J-K Flip-Flop with Set and Reset

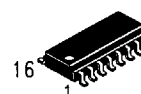
This device consists of two J-K flip-flop with individual set, reset, and clock inputs. Changes at the inputs are reflected at the outputs with the next low-to-high transition of the clock. Both the Q and Q outputs are available from each flip-flop

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2 to 6 V for HC devices
- Low Input Current: 1 μ A
- DC, AC parameters guaranteed from -55°C to 125°C

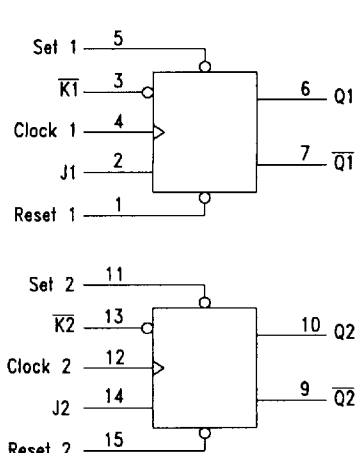
DV74HC109 DV74HCT109



N Suffix
Plastic DIP
AVG-003 Case

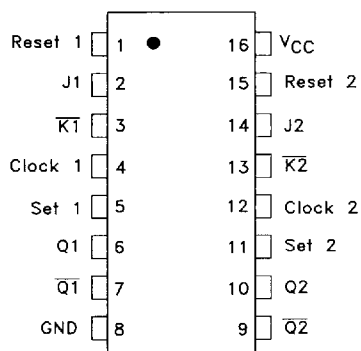


D Suffix
Plastic SOP
AVG-004 Case



PIN 16 = V_{CC}
PIN 8 = GND

PIN ASSIGNMENT



TRUTH TABLE

Inputs					Outputs	
Set	Reset	Clock	J	$\bar{K}$	Q	$\bar{Q}$
L	H	X	X	X	H	L
H	L	X	X	X	L	H
L	L	X	X	X	H*	H*
H	H	$\uparrow$	L	L	L	H
H	H	$\uparrow$	H	L	Toggle	
H	H	$\uparrow$	L	H	No Change	
H	H	$\uparrow$	H	H	H	L
H	H	L	X	X	No Change	

*Both outputs will remain high as long as Set and Reset are low, but the output states are unpredictable if Set and Reset go high simultaneously
 $\uparrow$ = Low to High Transition
 $\downarrow$ = High to Low Transition
 X = Don't Care

ABSOLUTE MAXIMUM RATINGS

Maximum ratings are those values beyond which damage to the device may occur.

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)	-1.5 to $V_{CC} + 1.5$	V
V_{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to $V_{CC} + 0.5$	V
I_{IN}	DC Input Current, per Pin	± 20	mA
I_{OUT}	DC Output Current, per Pin	± 25	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	± 50	mA
P_D	Power Dissipation in Still Air, Plastic DIP SOP Package	750 500	mW
T_{STG}	Storage Temperature Range	-65 to +150	°C
TL	Lead Temperature, 1mm from Case for 10 Seconds	260	°C

GUARANTEED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	DC Supply Voltage (Referenced to GND)	2.0	6.0	V
V _{IN} , V _{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V _{CC}	V
T _A	Ambient Temperature	-55	+125	°C
t _r , t _f	Input Rise and Fall Time V _{CC} =2.0V V _{CC} =4.0V V _{CC} =6.0V	0 0 0	1000 500 400	ns

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DC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V _{CC} V	Guaranteed Limits			Unit
				25°C to -55°C	≤85°C	≤125°C	
V _{IH}	Minimum High-Level Input Voltage	V _{OUT} = 0.1 V, I _{OUT} ≤ 20 μA or V _{OUT} = V _{CC} - 0.1 V	2.0 4.5 6.0	1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	V
V _{IL}	Maximum Low-Level Input Voltage	V _{OUT} = 0.1 V, I _{OUT} ≤ 20 μA or V _{OUT} = V _{CC} - 0.1 V	2.0 4.5 6.0	0.3 0.9 1.2	0.3 0.9 1.2	0.3 0.9 1.2	V
V _{OH}	Minimum High-Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 4.0 mA I _{OUT} ≤ 5.2 mA	4.5 6.0	3.98 5.48	3.84 5.34	3.7 5.2	
V _{OL}	Maximum Low-Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		V _{IN} = V _{IH} or V _{IL} , I _{OUT} ≤ 4.0 mA I _{OUT} ≤ 5.2 mA	4.5 6.0	0.26 0.26	0.33 0.33	0.40 0.40	V
I _{IN}	Maximum Input Leakage Current	V _{IN} = V _{CC} or GND	6.0	± 0.1	± 1.0	± 1.0	μA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND, I _{OUT} ≤ 0 μA	6.0	4.0	40	80	μA

AC ELECTRICAL CHARACTERISTICS over full operating conditions (C_L = 50 pF, Input t_r = t_f = 6 ns)

Symbol	Parameter	V _{CC} V	Guaranteed Limit			Unit
			25°C to -55°C	≤85°C	≤125°C	
f _{max}	Maximum Clock Frequency (50% Cycle)	2.0 4.5 6.0	6.0 30 35	4.8 24 28	4.0 20 24	MHz
t _{PLH} , t _{PHL}	Maximum Propagation Delay Time, Clock to Q or $\bar{Q}$	2.0 4.5 6.0	175 35 30	220 44 37	265 53 45	ns
t _{PLH} , t _{PHL}	Maximum Propagation Delay Time, Set or Reset to Q or $\bar{Q}$	2.0 4.5 6.0	230 46 39	290 58 49	345 69 59	ns
t _{TLH} , t _{THL}	Maximum Output Transition Time Any Output	2.0 4.5 6.0	75 15 13	95 19 16	110 22 19	ns
C _{IN}	Maximum Input Capacitance	—	10	10	10	pF

CPD	Power Dissipation Capacitance (Per Gate) Used to determine the no-load dynamic power consumption, P _D = C _{PD} V _{CC} ² f + I _{CC} V _{CC}	Typical @ 25°C, V _{CC} = 5 V	
		40	

TIMING REQUIREMENTS (Input $t_r=t_f=6$ ns)

Symbol	Parameter	V _{CC} V	Guaranteed Limit			Unit
			25°C to -55°C	≤85°C	≤125°C	
t _{su}	Minimum Setup Time, J or $\bar{K}$ to Clock	2.0	100	125	150	ns
		4.5	20	25	30	
		6.0	17	21	26	
t _h	Minimum Hold Time, Clock to J or $\bar{K}$	2.0	5	5	5	ns
		4.5	5	5	5	
		6.0	5	5	5	
t _{rec}	Minimum Recovery Time, Set or Reset Inactive to Clock	2.0	5	5	5	ns
		4.5	5	5	5	
		6.0	5	5	5	
t _w	Minimum Pulse Width, Set or Reset	2.0	80	100	120	ns
		4.5	16	20	24	
		6.0	14	17	20	
t _w	Minimum Pulse Width, Clock	2.0	80	100	120	ns
		4.5	16	20	24	
		6.0	14	17	20	

HCT- 109**DC ELECTRICAL CHARACTERISTICS**

Symbol	Parameter	Conditions	V _{CC} V	Guaranteed Limits						Unit
				25°C to -55°C		≤85°C		≤125°C		
				Min	Max	Min	Max	Min	Max	
V _{IH}	Minimum High-Level Input Voltage	V _{OUT} = 0.1 V or V _{CC} -0.1 V I _{OUT} ≤ 20 μA	4.5 5.5	2.00 2.00		2.00 2.00		2.00 2.00		V
V _{IL}	Maximum Low- Level Input Voltage	V _{OUT} =0.1 V or V _{CC} - 0.1 V I _{OUT} ≤ 20 μA	4.5 5.5		0.80 0.80		0.80 0.80		0.80 0.80	V
V _{OH}	Minimum High-Level Output Voltage	V _{IN} = V _{IL} or V _{IH} I _{OUT} ≤ 20 μA	4.5 5.5	4.40 5.40		4.40 5.40		4.40 5.40		V
		V _{IN} =V _{IL} or V _{IH} I _{OUT} ≤4.0 mA	4.5	3.98		3.84		3.70		V
V _{OL}	Maximum Low Level Output Voltage	V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 20 μA	4.5 5.5		0.1 0.1		0.1 0.1		0.1 0.1	V
		V _{IN} = V _{IH} or V _{IL} I _{OUT} ≤ 4.0mA	4.5		0.26		0.33		0.40	V
I _{IN}	Maximum Input Leakage Current	V _{IN} = V _{CC} or GND	5.5		± 0.1		± 1.0		± 1.0	μA
I _{CC}	Maximum Quiescent Supply Current	V _{IN} = V _{CC} or GND I _{OUT} = 0 μA	5.5		4.0		40		80	μA

Δ I _{CC}	Additional Quiescent Supply Current	V _{IN} =2.4V, Any One Input V _{IN} =V _{CC} or GND, Other Inputs I _{OUT} =0 μA	5.5	≥ -55°C		25°C to 125°C		mA
				2.9		2.4		

AC ELECTRICAL CHARACTERISTICS over full operating conditions (C_L=50pF, Input $t_r=t_f=6$ ns)

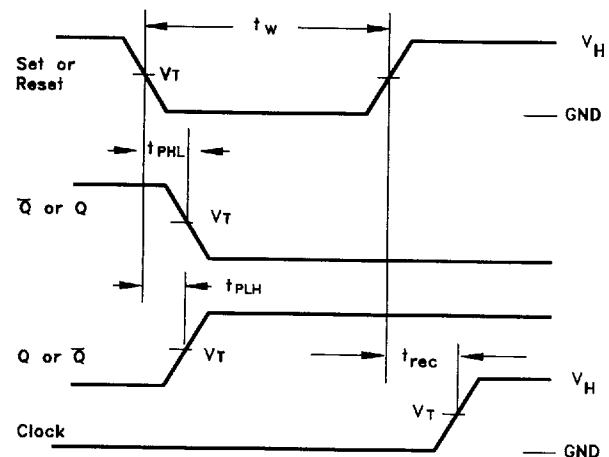
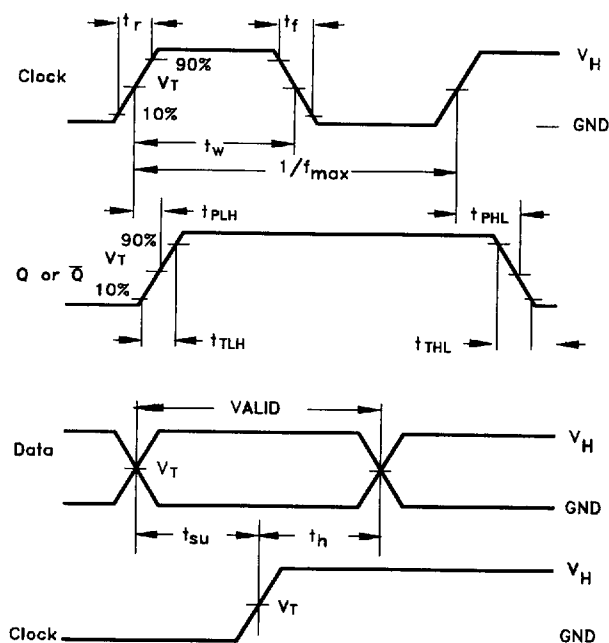
Symbol	Parameter	V _{CC} V	Guaranteed Limit			Unit
			25°C to -55°C	≤85°C	≤125°C	
f _{max}	Maximum Clock Frequency (50% Cycle)	5.0	30	24	20	MHz
t _{PLH} , t _{PHL}	Maximum Propagation Delay Time, Clock to Q or $\bar{Q}$	5.0	35	44	53	ns
t _{PLH} , t _{PHL}	Maximum Propagation Delay Time, Set or Reset to Q or $\bar{Q}$	5.0	46	58	69	ns
t _{TLH} , t _{THL}	Maximum Output Transition Time Any Output	5.0	15	19	22	ns
C _{IN}	Maximum Input Capacitance	—	10	10	10	pF

Symbol	Parameter	V _{CC} V	Guaranteed Limit			Unit
			25°C to -55°C	≤85°C	≤125°C	
C _{IN}	Maximum Input Capacitance	—	10	10	10	pF
C _{PD}	Power Dissipation Capacitance (Per Inverter) Used to determine the no-load dynamic power consumption, P _D = C _{PD} V _{CC} ² f + I _{CC} V _{CC}	Typical @ 25°C, V _{CC} = 5 V				
		15				pF

TIMING REQUIREMENTS (Input $t_r=t_f=6$ ns)

Symbol	Parameter	V _{CC}	Guaranteed Limit			Unit
			25°C to -55°C	≤85°C	≤125 °C	
t _{su}	Minimum Setup Time, J or $\bar{K}$ to Clock	5.0	20	25	30	ns
t _h	Minimum Hold Time, Clock to J or $\bar{K}$	5.0	5	5	5	ns
t _{rec}	Minimum Recovery Time, Set or Reset Inactive to Clock	5.0	5	5	5	ns
t _w	Minimum Pulse Width, Set or Reset	5.0	16	20	24	ns
t _w	Minimum Pulse Width, Clock	5.0	16	20	24	ns

SWITCHING WAVEFORMS



Input and Output Threshold Voltage: $V_T = 50\% V_{CC}$ for HC, 1.3V for HCT, $V_H = V_{CC}$ for HC, 3V for HCT